VS-UFH60BA65

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Vishay Semiconductors

Insulated Single Phase Hyperfast Bridge (Power Modules), 60 A



PRIMARY CHARACTERISTICS							
V _{RRM}	650 V						
I _O at T _C = 123 °C	60 A						
t _{rr}	63 ns						
Туре	Modules - Bridge, Hyperfast						
Package	SOT-227						
Circuit configuration	Single phase bridge						

FEATURES

- Hyperfast and soft recovery characteristic
- Electrically isolated base plate
- Simplified mechanical designs, rapid assembly COMPLIANT
- High operation junction temperature (T_J max. = 175 $^{\circ}$ C)
- Designed and qualified for industrial and consumer level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

ABSOLUTE MAXIMUM RATINGS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I		60	А				
IO	T _C	123	°C				
I _{FSM}	50 Hz	360	А				
	60 Hz	377	A				
l ² t	50 Hz	648	A ² s				
1-1	60 Hz	589	A-5				
V _{RRM}		650	V				
TJ		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J MAXIMUM mA					
UFH60BA65	65	650	700	2					

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	YMBOL TEST CONDITIONS MIN. TYP.				UNITS		
Cathode to anode breakdown voltage	V _{BR}	I _R = 250 μA	650	-	-	V		
Forward voltage, per diode	V _{FM}	I _F = 60 A	-	1.7	2.35	v		
Reverse leakage current, per leg	I _{RM}	V _R = 650 V	-	1.0	100			
Reverse leakage current, per leg		V _R = 650 V, T _J = 150 °C	-	250	-	μA		
RMS isolation voltage base plate	VISOL	f = 50 Hz, any terminal to case, t = 1 min	2500	-	-	V		

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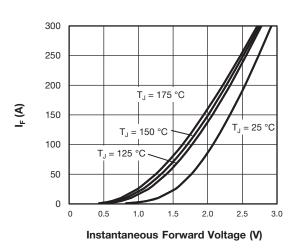
FORWARD CONDUCTION							
PARAMETER	SYMBOL		S	VALUES	UNITS		
Maximum DC output current	-	Resistive or ind	Resistive or inductive load			А	
at case temperature	Ι _Ο				123	°C	
		t = 10 ms	No voltage		360		
Maximum peak, one-cycle		t = 8.3 ms	reapplied		377	A	
non-repetitive forward current	I _{FSM}	t = 10 ms	100 % V _{RRM}	-	303		
		t = 8.3 ms	reapplied	- Initial T _J = 25 °C	317		
	l ² t	t = 10 ms	No voltage		648	A ² s	
Maximum 12t for fusing		t = 8.3 ms	reapplied		589		
Maximum I ² t for fusing		t = 10 ms	100 % V _{BBM}		458		
		t = 8.3 ms	reapplied		417		
Maximum I²√t for fusing	l²√t	$I^{2}t$ for time $t_{x} =$	$I_2 \sqrt{t} x \sqrt{t_x}; 0.1 \le t_x \le 1$	0 ms, V _{RRM} = 0 V	6.4	kA²√s	
Low level of threshold voltage, per leg	V _{F(T0)1}	(16 7 0/ x - x l		Tumavinaum	16.49	V	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)}) < I < π x I _{F(AV)} , T _J = T _J maximum		0.88	mΩ		
High level of threshold voltage, per leg	V _{F(T0)2}				15.87	V	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 1.16			1.16	mΩ	
Maximum forward voltage, per diode	V _{FM}	I _F = 60 A 2.35			V		

RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
	+	T _J = 25 °C, I _F = 50 A, V _R = 200 V, dI _F /dt = 200 A/μs	63	20				
Typical reverse recovery time, per diode	t _{rr}	$T_J = 125 \text{ °C}, I_F = 50 \text{ A}, V_R = 200 \text{ V},$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$	134	ns				
Typical reverse recovery current, per diode	I _{rr}	T _J = 25 °C, I _F = 50 A, V _R = 200 V, dI _F /dt = 200 A/μs	4.1	А				
		$T_J = 125 \text{ °C}, I_F = 50 \text{ A}, V_R = 200 \text{ V},$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$	11.4	A	$\frac{dI_R}{dt}$ Q_{rr}			
Typical reverse recovery charge, per diode	Q _{rr}	T _J = 25 °C, I _F = 50 A, V _R = 200 V, dI _F /dt = 200 A/μs	130	nC	dt V I _{RM(REC)}			
		$T_J = 125 \text{ °C}, I_F = 50 \text{ A}, V_R = 200 \text{ V},$ $dI_F/dt = 200 \text{ A}/\mu \text{s}$	765	ΠC				
Typical junction capacitance	CT	V _R = 650 V	77	pF				

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance junction to case	ermal resistance junction to case R _{thJC}		-	-	0.91	°C/W	
Thermal resistance case to heatsink	R _{thCS}	Flat, greased surface	-	0.1	-	0/11	
Weight			-	30	-	g	
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)	
Mounting torque		Torque to heatsink	-	-	1.3 (11.5)	Nm (lbf.in)	
Case style			SOT-227				

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Fig. 1 - Typical Forward Voltage Characteristics

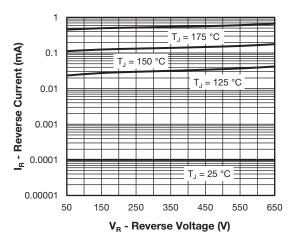


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Diode)

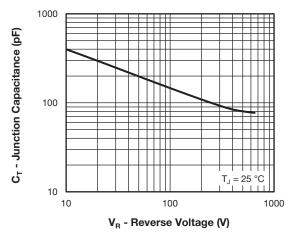


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Diode)

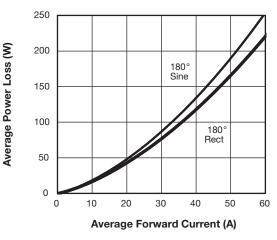
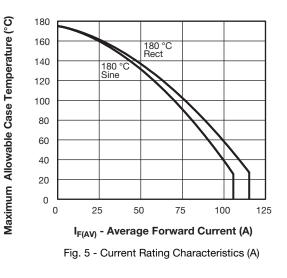
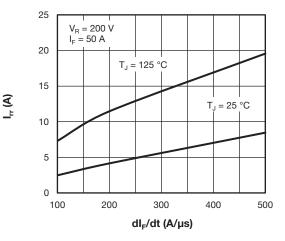


Fig. 4 - Forward Power Loss Characteristics







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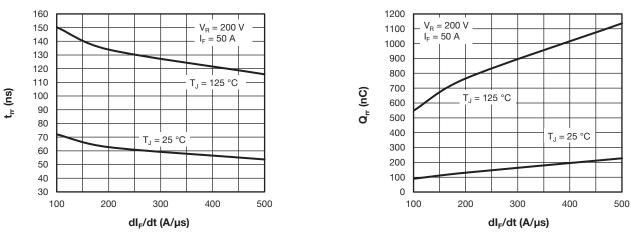


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

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Fig. 8 - Reverse Recovery Charge vs. dl_F/dt

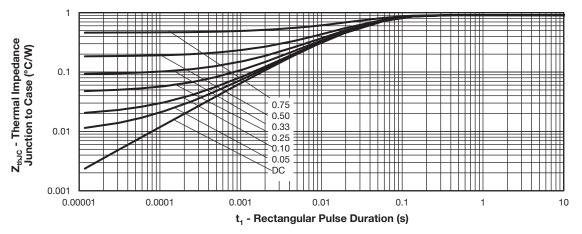


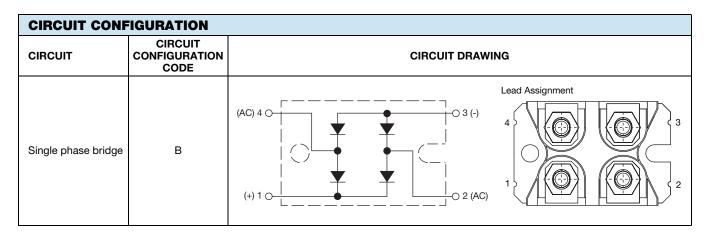
Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt (Per Diode)





ORDERING INFORMATION TABLE

Device code	vs	-	UF	н	60	В	Α	65
)	2	3	4	5	6	7
	1 2 3 4 5		Ultra Hype Curr Circe	a fast rec er fast F ent ratir uit confiq	RED Pť ng (60 = guration	[®] diffuse 60 A) :		
	6	-	B = Single phase bridge Package indicator:					
	7	-	A = SOT-227, standard insulated base Voltage rating (65 = 650 V)					



LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95423						
Packaging information	www.vishay.com/doc?95425						



SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

• Controlling dimension: millimeter



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